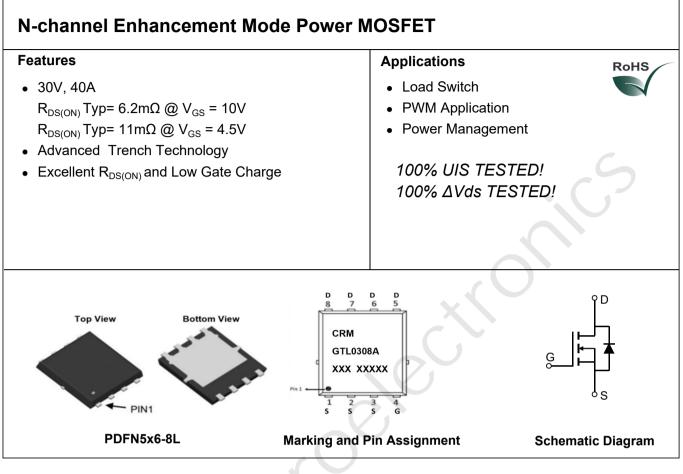


## Description



### Package Marking and Ordering Information

Device Marking	Device	Outline	Package	Reel Size	Reel(pcs)	Per Carton (pcs)
CRMGTL0308A	CRMGTL0308A	TAPING	PDFN5x6-8L	13"	5000	50000

#### Absolute Maximum Ratings (@ T<sub>J</sub> = 25°C unless otherwise specified)

Symbol	Parameter		Value	Units
V <sub>DS</sub>	Drain-to-Source Voltage		30	V
V <sub>GS</sub>	Gate-to-Source Voltage		±20	V
	Continuous Dusin Current	T <sub>C</sub> = 25°C	40	
Ι <sub>D</sub>	Continuous Drain Current	T <sub>C</sub> = 100°C	24	A
I <sub>DM</sub>	Pulsed Drain Current <sup>(1)</sup>		160	А
E <sub>AS</sub>	Single Pulsed Avalanche Energy <sup>(2)</sup>		42	mJ
P <sub>D</sub>	Power Dissipation	T <sub>C</sub> = 25°C	24	W
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case		5.2	°C/W
$T_{J},T_{STG}$	Junction & Storage Temperature F	Range	-55 to 150	°C



#### Electrical Characteristics (T<sub>J</sub> = 25°C unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Off Cha	racteristics		<u>_</u>		<u> </u>	
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	30	-	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V	-	-	1.0	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	±100	nA
On Cha	racteristics				C	
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0	1.6	2.2	V
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 25A	-	6.2	8.1	mΩ
R <sub>DS(ON)</sub>	Static Drain-Source ON-Resistance <sup>(3)</sup>	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 15A	-	11.0	14.3	mΩ
Dynami	ic Characteristics					
C <sub>iss</sub>	Input Capacitance		-	1310	-	pF
C <sub>oss</sub>	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$	-	142	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1MHz	- \	121	-	pF
$Q_{g}$	Total Gate Charge		-	23	-	nC
$Q_{gs}$	Gate Source Charge	$V_{GS} = 0$ to 10V $V_{DS} = 15V, I_D = 20A$	<u> </u>	4.5	-	nC
$Q_{gd}$	Gate Drain("Miller") Charge	$v_{DS} = 15V, I_D = 20A$	-	5.5	-	nC
Switchi	ing Characteristics					
t <sub>d(on)</sub>	Turn-On DelayTime		-	7	-	ns
t,	Turn-On Rise Time	V <sub>GS</sub> = 10V, V <sub>DD</sub> = 15V	-	15	-	ns
$t_{d(off)}$	Turn-Off DelayTime	$I_D$ = 15A, $R_{GEN}$ = 3 $\Omega$	-	25	-	ns
t <sub>f</sub>	Turn-Off Fall Time		-	6	-	ns
Drain-S	ource Diode Characteristics and I	Max Ratings				
l <sub>s</sub>	Maximum Continuous Drain to Source Diod	de Forward Current	-	-	40	А
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Fo	orward Current	-	-	160	Α
$V_{\rm SD}$	Drain to Source Diode Forward Voltage	V <sub>GS</sub> = 0V, I <sub>S</sub> = 15A	-	-	1.2	V
trr	Body Diode Reverse Recovery Time		-	10	-	ns
Qrr	Body Diode Reverse Recovery Charge	I <sub>F</sub> = 20A, di/dt = 100A/us	-	3	-	nC

Notes: 1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature.

2.  $E_{AS}$  condition: Starting T<sub>J</sub>=25C, V<sub>DD</sub>=15V, V<sub>G</sub>=10V, R<sub>G</sub>=25ohm, L=0.5mH, I<sub>AS</sub>=13A

3. Pulse Test: Pulse Width  ${\leqslant}300\mu s,$  Duty Cycle  ${\leqslant}0.5\%.$ 



# CRMGTL0308A

## **Test Circuit**

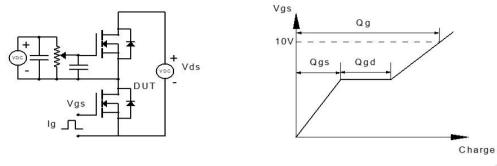


Figure 1: Gate Charge Test Circuit & Waveform

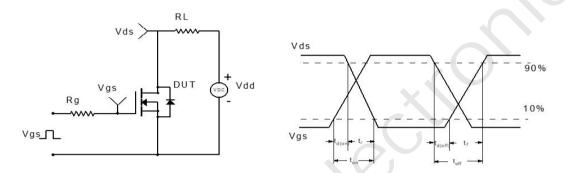
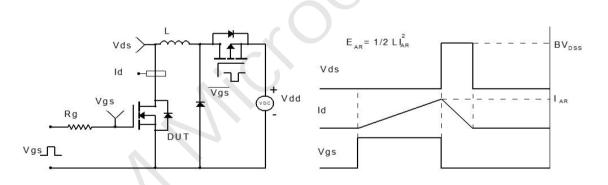
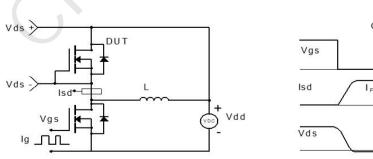
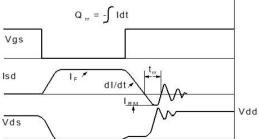


Figure 2: Resistive Switching Test Circuit & Waveform





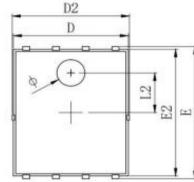


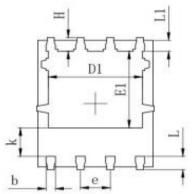


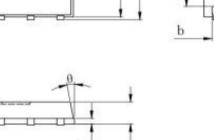




## Package Mechanical Data(PDFN5X6-8L)







SYMBOL		MILLIMETER		
	MIN	Typ.	MAX	
Α	0.900	1.000	1,100	
A1	0.254 REF.			
A2	0~0.05			
D	4, 824	4.900	4.976	
D1	3, 910	4.010	4.110	
D2	4.924	5.000	5.076	
E	5. 924	6.000	6.076	
E1	3. 375	3.475	3.575	
E2	5. 674	5.750	5.826	
b	0.350	0.400	0.450	
е		1.270 TYP.		
L	0. 534	0.610	0.686	
L1	0, 424	0.500	0.576	
1.2	1.800 REF.			
k	1.190	1,290	1.390	
Н	0.549	0.625	0.701	
θ	8*	10"	12°	
ф	1.100	1.200	1.300	
d		2	0.100	

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